NSN 5961-01-131-3836

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View Online at https://aerobasegroup.com/nsn/5961-01-131-3836 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.350 inches and 0.370 inches **End Application:** 6665-00-069-8906 80058 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, collector-to-base, emitter open and 200.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release5477 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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